

KSA1013OBU

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KSA1013OBU Information

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	Manufacturer	Fairchild/ON Semiconductor
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
	Description	TRANS PNP 160V 1A TO-92L
	Package	TO-226-3, TO-92-3 Long Body
		For the pricing/inventory/lead time, please contact
		us
For Reference Only		Website: https://www.heisener.com
		E-mail: salesdept@heisener.com



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



KSA1013OBU Specifications

Manufacturer Part NumberKSA1013OBUManufacturerFairchild/ON SemiconductorCategoryDiscrete Semiconductor ProductsTransistor Selipolar (BJT) - SinglePackageTo-226-3, TO-92-3 Long BodySeries-Transistor TypePNPCurrent - Collector (Ic) (Max)IAVoltage - Collector Emitter Breakdown (Max)I60VVec Saturation (Max) @ Ib, IcIJADC Current Gain (hFE) (Min) @ Ic, VeeI00 @ 200mA, 5VPower - Max900mWFrequency - TransitionSIOHZOperating TemperatureISOC (TJ)Monting TypeInfougational (Infougational Infougational Infougat	
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Frequency - Transition50MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 Long Body	
Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 Long Body	
Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 Long Body	
Package / Case TO-226-3, TO-92-3 Long Body	
Supplier Device Package TO-92-3	
	Report errors?

KSA1013OBU Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

KSA1013OBU Payment Methods



KSA1013OBU Shipping Methods



If you have any question about KSA1013OBU, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com